

F1
a barrier metal layer interposed between said electrode and said one of the source and drain regions to prevent a direct contact therebetween;
a transparent electrode electrically connected to said thin film transistor;
an electroluminescence layer comprising an organic material disposed adjacent to said transparent electrode, and
a peripheral driving circuit comprising another thin film transistor formed over said substrate,
wherein said barrier metal layer comprises titanium.

F2
12. (Amended) The display device according to claim 1 wherein said barrier metal layer comprises titanium nitride where a concentration of nitrogen is less than 50 atm%.

F3
14. (Amended) The display device according to claim 9 wherein said conductive layer comprises titanium nitride where a concentration of nitrogen is less than 50 atm%.

Please add new claims 20 and 21:

--20. The display device according to claim 12 wherein said concentration of nitrogen is not higher than 15 atm%.

F4
21. The display device according to claim 9 wherein said conductive layer comprises titanium nitride where a concentration of nitrogen is not higher than 15 atm%.--
